

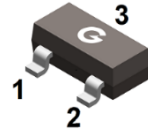
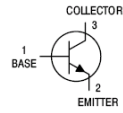
Features

- Complementary to S9015
- Excellent h_{FE} linearity

HF

Mechanical Data

- Case: SOT-23
- Molding compound: UL flammability classification rating 94V-0
- Terminals: Tin-plated; solderability per MIL-STD-202, Method 208



SOT-23

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
S9014	SOT-23	3000 pcs / Tape & Reel	J6

Maximum Ratings (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	45	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current (Continuous)	I_C	100	mA
Collector Current (Peak)	I_{CM}	200	mA

Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation	P_D	200	mW
Thermal Resistance Junction-to-Air ^{*1}	$R_{\theta JA}$	250	$^\circ\text{C/W}$
Thermal Resistance Junction-to-Case ^{*1}	$R_{\theta JC}$	150	$^\circ\text{C/W}$
Thermal Resistance Junction-to-Lead ^{*1}	$R_{\theta JL}$	180	$^\circ\text{C/W}$
Operating Junction Temperature	T_J	-55 ~ +150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 ~ +150	$^\circ\text{C}$

Note 1: The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 100\mu\text{A}$, $I_E = 0$	50	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 0.1\text{mA}$, $I_B = 0$	45	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 100\mu\text{A}$, $I_C = 0$	5	-	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB} = 50\text{V}$, $I_E = 0$	-	-	0.1	μA
Collector Cut-off Current	I_{CEO}	$V_{CE} = 35\text{V}$, $I_B = 0$	-	-	0.1	μA
Emitter-base Cut-off Current	I_{EBO}	$V_{EB} = 3\text{V}$, $I_C = 0$	-	-	0.1	μA
DC Current Gain	h_{FE}	$V_{CE} = 5\text{V}$, $I_C = 1\text{mA}$	200	-	1000	-
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 100\text{mA}$, $I_B = 5\text{mA}$	-	-	0.3	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 100\text{mA}$, $I_B = 5\text{mA}$	-	-	1.0	V
Base Emitter Voltage	$V_{BE(ON)}$	$V_{CE} = 5\text{V}$, $I_C = 2\text{mA}$	-	-	0.70	V
Transition Frequency	f_T	$V_{CE} = 6\text{V}$, $I_C = 20\text{mA}$ $f = 30\text{MHz}$	-	150	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = 10\text{V}$, $I_E = 0$ $f = 1\text{MHz}$	-	-	3.5	pF

Classification of h_{FE}

Rank	L	H
Range	200-450	450-1000

Ratings and Characteristic Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

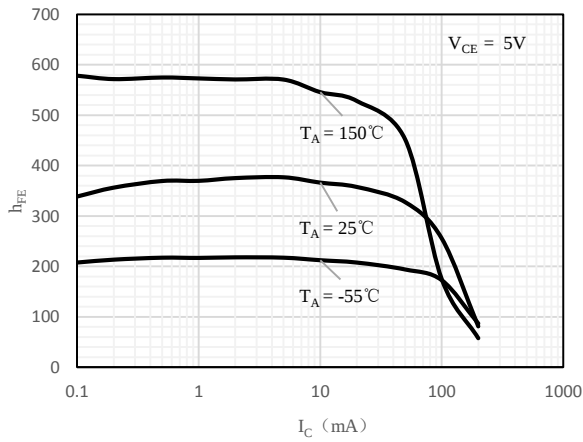


Fig 1 h_{FE} vs. I_C

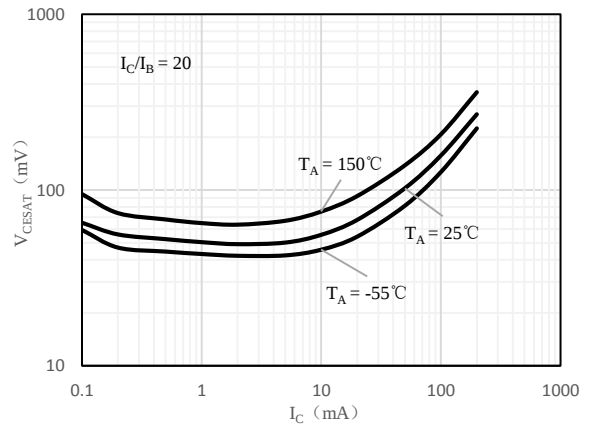


Fig 2 $V_{CE(sat)}$ vs. I_C

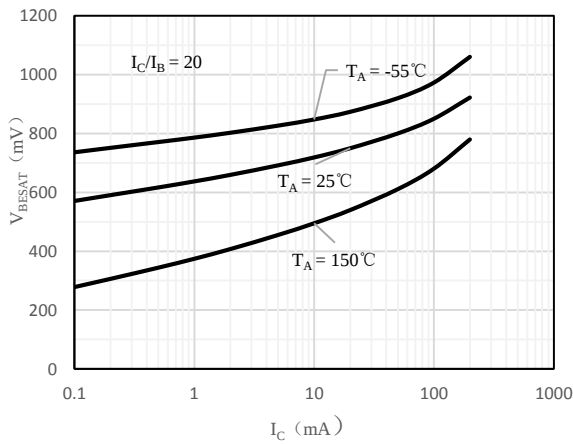


Fig 3 $V_{BE(sat)}$ vs. I_C

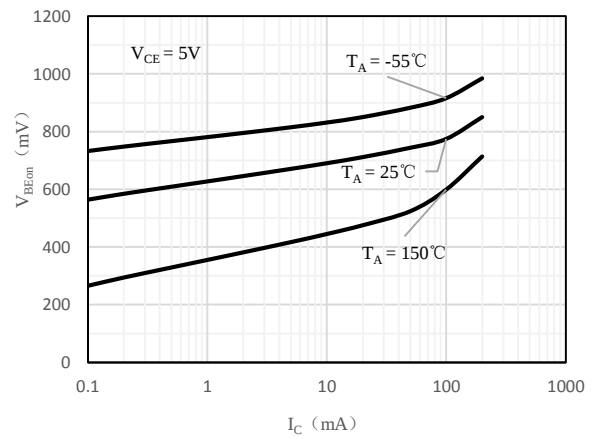


Fig 4 $V_{BE(on)}$ vs. I_C

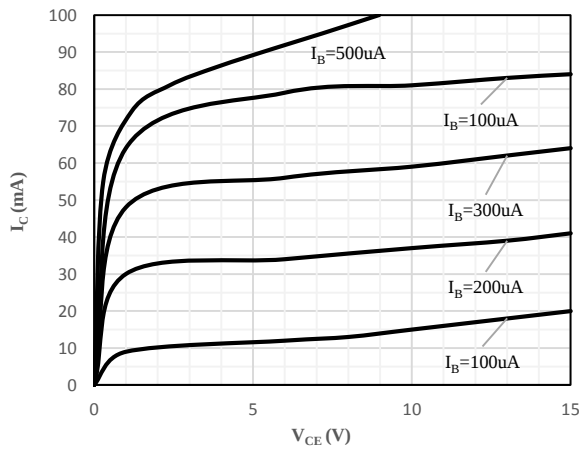


Fig 5 I_C vs. V_{CE}

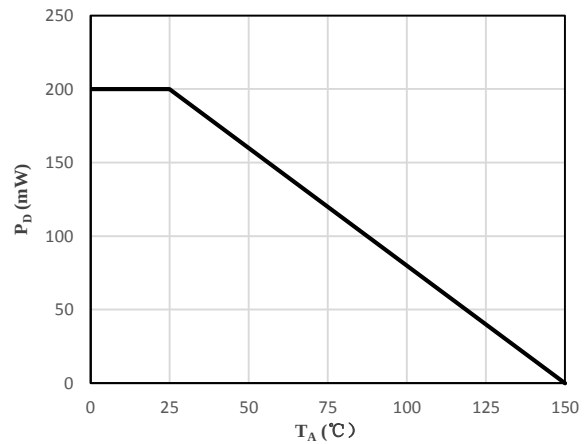
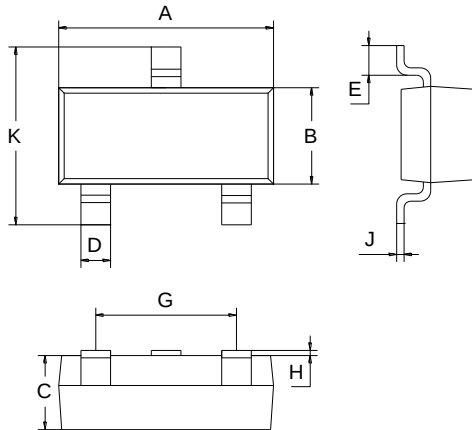


Fig 6 Steady State Power Derating

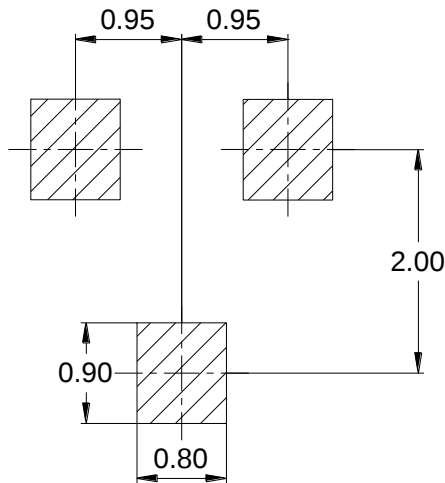
Package Outline Dimensions (Unit: mm)



SOT-23		
Dimension	Min.	Max.
A	2.70	3.10
B	1.10	1.50
C	0.9	1.1
D	0.3	0.5
E	0.35	0.48
G	1.80	2.00
H	0.02	0.1
J	0.05	0.15
K	2.20	2.60

Package Outline Dimensions (Unit: mm)

SOT-23



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